

# SN74AVCH16T245 16-Bit Dual-Supply Bus Transceiver with Configurable Level-Shifting / Voltage Translation and Tri-State Outputs

## 1 Features

- $V_{CC}$  Isolation Feature – If Either  $V_{CC}$  Input is at GND, Both Ports are in the High-Impedance State
- Control Inputs  $V_{IH}/V_{IL}$  Levels Are Referenced to  $V_{CCA}$  Voltage
- Overvoltage-Tolerant Inputs and Outputs Allow Mixed Voltage-Mode Data Communications
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.2 V to 3.6 V Power-Supply Range
- $I_{off}$  Supports Partial-Power-Down Mode Operation
- I/Os are 4.6 V Tolerant
- Bus Hold on Data Inputs Eliminates the Need for External Pullup and Pulldown Resistors
- Maximum Data Rates
  - 380 Mbps (1.8 V to 3.3 V Level-Shifting)
  - 200 Mbps (<1.8 V to 3.3 V Level-Shifting)
  - 200 Mbps (Level-Shifting to 2.5 V or 1.8 V)
  - 150 Mbps (Level-Shifting to 1.5 V)
  - 100 Mbps (Level-Shifting to 1.2 V)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 8000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

## 2 Applications

- Personal Electronics
- Industrial
- Enterprise
- Telecom

## 3 Description

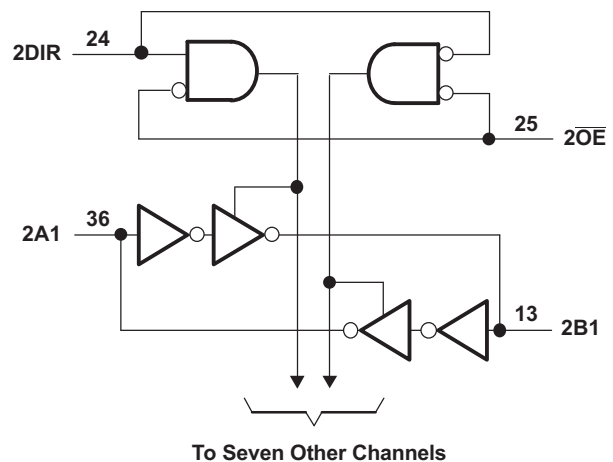
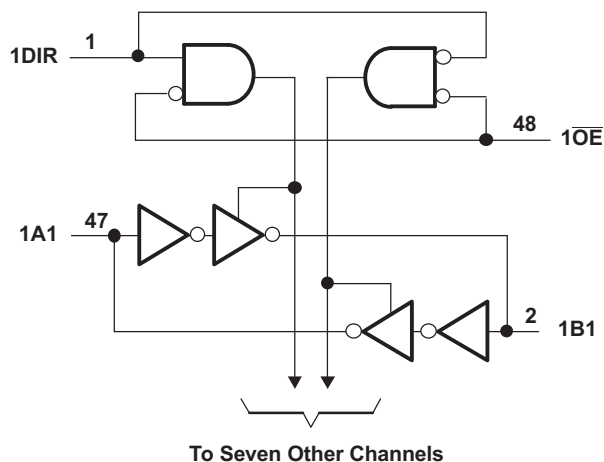
This 16-bit noninverting bus transceiver uses two separate configurable power-supply rails. The SN74AVCH16T245 device is optimized to operate with  $V_{CCA}/V_{CCB}$  set at 1.4 V to 3.6 V. The device is operational with  $V_{CCA}/V_{CCB}$  as low as 1.2 V. The A port is designed to track  $V_{CCA}$ .  $V_{CCA}$  accepts any supply voltage from 1.2 V to 3.6 V. The B port is designed to track  $V_{CCB}$ .  $V_{CCB}$  accepts any supply voltage from 1.2 V to 3.6 V. This allows for universal low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes.

### Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)
SN74AVCH16T245	TSSOP (48)	12.50 mm x 6.10 mm
	TVSOP (48)	9.70 mm x 4.40 mm
	BGA MICROSTAR JUNIOR (56)	7.00 mm x 4.50 mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

### Logic Diagram (Positive Logic)



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision C (February 2015) to Revision D	Page
• Updated Pin Functions table. ....	4

Changes from Revision B (May 2006) to Revision C	Page
• Added <i>ESD Ratings</i> table, <i>Feature Description</i> section, <i>Device Functional Modes</i> , <i>Application and Implementation</i> section, <i>Power Supply Recommendations</i> section, <i>Layout</i> section, <i>Device and Documentation Support</i> section, and <i>Mechanical, Packaging, and Orderable Information</i> section .....	1

## 5 Description (continued)

The SN74AVCH16T245 control pins (1DIR, 2DIR,  $\overline{1OE}$ , and  $\overline{2OE}$ ) are supplied by  $V_{CCA}$ .

The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down. This device is fully specified for partial-power-down applications using  $I_{off}$ .

The  $V_{CC}$  isolation feature ensures that if either  $V_{CC}$  input is at GND, then both ports are in the high-impedance state.

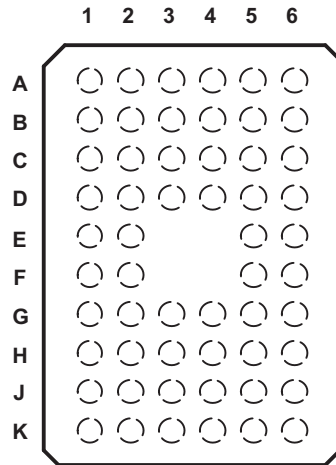
Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

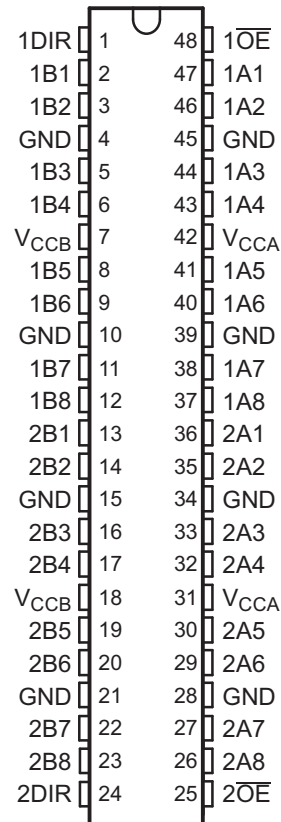
The SN74AVCH16T245 is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable ( $\overline{OE}$ ) input can be used to disable the outputs so the buses are effectively isolated.

## 6 Pin Configuration and Functions

**GQL or ZQL Package**  
56-Pin BGA MICROSTAR JUNIOR  
Top View



**DGG or DGV Package**  
48-Pin TSSOP or TVSOP  
Top View



### Pin Functions

PIN			I/O	DESCRIPTION
NAME	TSSOP TVSOP	BGA MICROSTAR		
1DIR, 2DIR	1, 24	A1, K1	I	Direction-control signal
1B1 to 1B8	2, 3, 5, 6, 8, 9, 11, 12	B2, B1, C2, C1, D2, D1, E2, E1	I/O	Input/Output. Referenced to $V_{CCB}$
2B1 to 2B8	13, 14, 16, 17, 19, 20, 22, 23	F1, F2, G1, G2, H1, H2, J1, J2	I/O	Input/Output. Referenced to $V_{CCB}$
GND	4, 10, 15, 21, 45, 39, 34, 28	B3, D3, G3, J3, J4, G4, D4, B4	—	Ground
$V_{CCB}$	7, 18	C3, H3	—	B-port supply voltage. $1.2\text{ V} \leq V_{CCB} \leq 3.6\text{ V}$
$\overline{1OE}$ , $\overline{2OE}$	48, 25	A6, K6	—	Tri-State output-mode enables. Pull $\overline{OE}$ high to place all outputs in Tri-State mode. Referenced to $V_{CCA}$
1A1 to 1A8	47, 46, 44, 43, 41, 40, 38, 37	B5, B6, C5, C6, D5, D6, E5, E6	I/O	Input/Output. Referenced to $V_{CCA}$
2A1 to 2A8	36, 35, 33, 32, 30, 29, 27, 26	F6, F5, G6, G5, H6, H5, J6, J5	I/O	Input/Output. Referenced to $V_{CCA}$
$V_{CCA}$	42, 31	C4, H4	—	A-port supply voltage. $1.2\text{ V} \leq V_{CCB} \leq 3.6\text{ V}$
N.C.	—	A2, A3, A4, A5, K2, K3, K4, K5	—	No internal connection

## 7 Specifications

### 7.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted<sup>(1)</sup>)

		MIN	MAX	UNIT	
$V_{CCA}$ $V_{CCB}$	Supply voltage	-0.5	4.6	V	
$V_I$	Input voltage <sup>(2)</sup>	I/O ports (A port)	-0.5	4.6	V
		I/O ports (B port)	-0.5	4.6	
		Control inputs	-0.5	4.6	
$V_O$	Voltage applied to any output in the high-impedance or power-off state <sup>(2)</sup>	A port	-0.5	4.6	V
		B port	-0.5	4.6	
$V_O$	Voltage applied to any output in the high or low state <sup>(2)(3)</sup>	A port	-0.5	$V_{CCA} + 0.5$	V
		B port	-0.5	$V_{CCB} + 0.5$	
$I_{IK}$	Input clamp current	$V_I < 0$	-50	mA	
$I_{OK}$	Output clamp current	$V_O < 0$	-50	mA	
$I_O$	Continuous output current		±50	mA	
	Continuous current through each $V_{CCA}$ , $V_{CCB}$ , and GND		±100	mA	
$T_J$	Junction temperature	-40	150	°C	
$T_{stg}$	Storage temperature	-65	150	°C	

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input voltage ( $V_I$ ) and output negative-voltage ( $V_O$ ) ratings may be exceeded if the input and output current ratings are observed.
- (3) The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.

### 7.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 <sup>(1)</sup>	±8000
		Charged-device model (CDM), per JEDEC specification JESD22-C101 <sup>(2)</sup>	±1000
		Machine model (A115-A)	±200

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 500-V HBM is possible with the necessary precautions.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process. Manufacturing with less than 250-V CDM is possible with the necessary precautions.

### 7.3 Recommended Operating Conditions

 over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup> <sup>(2)</sup> <sup>(3)</sup>

		$V_{CCI}$	$V_{CCO}$	MIN	MAX	UNIT
$V_{CCA}$	Supply voltage			1.2	3.6	V
$V_{CCB}$	Supply voltage			1.2	3.6	V
$V_{IH}$	High-level input voltage	Data inputs <sup>(4)</sup>	1.2 V to 1.95 V	$V_{CCI} \times 0.65$		V
			1.95 V to 2.7 V	1.6		
			2.7 V to 3.6 V	2		
$V_{IL}$	Low-level input voltage	Data inputs <sup>(4)</sup>	1.2 V to 1.95 V	$V_{CCI} \times 0.35$		V
			1.95 V to 2.7 V	0.7		
			2.7 V to 3.6 V	0.8		
$V_{IH}$	High-level input voltage	DIR (referenced to $V_{CCA}$ ) <sup>(5)</sup>	1.2 V to 1.95 V	$V_{CCA} \times 0.65$		V
			1.95 V to 2.7 V	1.6		
			2.7 V to 3.6 V	2		
$V_{IL}$	Low-level input voltage	DIR (referenced to $V_{CCA}$ ) <sup>(5)</sup>	1.2 V to 1.95 V	$V_{CCA} \times 0.35$		V
			1.95 V to 2.7 V	0.7		
			2.7 V to 3.6 V	0.8		
$V_I$	Input voltage			0	3.6	V
$V_O$	Output voltage	Active state		0	$V_{CCO}$	V
		Tri-State		0	3.6	
$I_{OH}$	High-level output current		1.2 V	-3		mA
			1.4 V to 1.6 V	-6		
			1.65 V to 1.95 V	-8		
			2.3 V to 2.7 V	-9		
			3 V to 3.6 V	-12		
$I_{OL}$	Low-level output current		1.2 V	3		mA
			1.4 V to 1.6 V	6		
			1.65 V to 1.95 V	8		
			2.3 V to 2.7 V	9		
			3 V to 3.6 V	12		
$\Delta t/\Delta v$	Input transition rise or fall rate				5	ns/V
$T_A$	Operating free-air temperature			-40	85	°C

(1)  $V_{CCI}$  is the  $V_{CC}$  associated with the input port.

(2)  $V_{CCO}$  is the  $V_{CC}$  associated with the output port.

(3) All unused data inputs of the device must be held at  $V_{CCI}$  or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, [SCBA004](#).

(4) For  $V_{CCI}$  values not specified in the data sheet,  $V_{IH}$  min =  $V_{CCI} \times 0.7$  V,  $V_{IL}$  max =  $V_{CCI} \times 0.3$  V.

(5) For  $V_{CCA}$  values not specified in the data sheet,  $V_{IH}$  min =  $V_{CCA} \times 0.7$  V,  $V_{IL}$  max =  $V_{CCA} \times 0.3$  V.

### 7.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>	SN74AVCH16T245			UNIT	
	TSSOP (DGG)	TVSOP (DGV)	ZQL/GQL (BGA MICROSTAR JUNIOR)		
	48 PINS	48 PINS	56 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	82.5	69.9	64.6	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	34.2	23.9	16.6	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	45.1	36.6	30.8	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	2.7	1.7	0.9	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	44.6	36.2	64.6	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

## 7.5 Electrical Characteristics

over recommended operating free-air temperature range (unless otherwise noted)<sup>(1)(2)</sup>

PARAMETER	TEST CONDITIONS		V <sub>CCA</sub>	V <sub>CCB</sub>	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to 85°C		UNIT
					MIN	TYP	MAX	MIN	MAX	
V <sub>OH</sub>		V <sub>I</sub> = V <sub>IH</sub>	1.2 V to 3.6 V	1.2 V to 3.6 V				V <sub>CCO</sub> - 0.2		V
			1.2 V	1.2 V	0.95					
			1.4 V	1.4 V		1.05				
			1.65 V	1.65 V		1.2				
			2.3 V	2.3 V		1.75				
			3 V	3 V		2.3				
V <sub>OL</sub>		V <sub>I</sub> = V <sub>IL</sub>	1.2 V to 3.6 V	1.2 V to 3.6 V				0.2		V
			1.2 V	1.2 V	0.15					
			1.4 V	1.4 V		0.35				
			1.65 V	1.65 V		0.45				
			2.3 V	2.3 V		0.55				
			3 V	3 V		0.7				
I <sub>I</sub>	Control inputs	V <sub>I</sub> = V <sub>CCA</sub> or GND	1.2 V to 3.6 V	1.2 V to 3.6 V	±0.025	±0.25		±1	µA	
I <sub>BHL</sub> <sup>(3)</sup>		V <sub>I</sub> = 0.42 V	1.2 V	1.2 V	25				µA	
			1.4 V	1.4 V	15					
			1.65 V	1.65 V	25					
			2.3 V	2.3 V	45					
			3.3 V	3.3 V	100					
I <sub>BHH</sub> <sup>(4)</sup>		V <sub>I</sub> = 0.78 V	1.2 V	1.2 V	-25			µA		
			1.4 V	1.4 V	-15					
			1.65 V	1.65 V	-25					
			2.3 V	2.3 V	-45					
			3.3 V	3.3 V	-100					
I <sub>BHLO</sub> <sup>(5)</sup>		V <sub>I</sub> = 0 to V <sub>CC</sub>	1.2 V	1.2 V	50			µA		
			1.6 V	1.6 V	125					
			1.95 V	1.95 V	200					
			2.7 V	2.7 V	300					
			3.6 V	3.6 V	500					
I <sub>BHHO</sub> <sup>(6)</sup>		V <sub>I</sub> = 0 to V <sub>CC</sub>	1.2 V	1.2 V	-50			µA		
			1.6 V	1.6 V	-125					
			1.95 V	1.95 V	-200					
			2.7 V	2.7 V	-300					
			3.6 V	3.6 V	-500					
I <sub>off</sub>	A port	V <sub>I</sub> or V <sub>O</sub> = 0 to 3.6 V	0 V	0 to 3.6 V	±0.1	±2.5		±5	µA	
	B port		0 to 3.6 V	0 V	±0.1	±2.5		±5		
I <sub>OZ</sub> <sup>(7)</sup>	A or B port	V <sub>O</sub> = V <sub>CCO</sub> or GND, V <sub>I</sub> = V <sub>CCI</sub> or GND	$\overline{OE} = V_{IH}$	3.6 V	3.6 V	±0.5	±2.5		±5	µA
	B port		$\overline{OE} = \text{don't care}$	0 V	3.6 V				±5	
	A port			3.6 V	0 V				±5	
I <sub>CCA</sub>		V <sub>I</sub> = V <sub>CCI</sub> or GND, I <sub>O</sub> = 0	1.2 V to 3.6 V	1.2 V to 3.6 V				25	µA	
			0 V	3.6 V				-5		
			3.6 V	0 V				25		

(1) V<sub>CCI</sub> is the V<sub>CC</sub> associated with the input port.

(2) V<sub>CCO</sub> is the V<sub>CC</sub> associated with the output port.

(3) The bus-hold circuit can sink at least the minimum low sustaining current at V<sub>IL</sub> max. I<sub>BHL</sub> should be measured after lowering V<sub>IN</sub> to GND and then raising it to V<sub>IL</sub> max.

(4) The bus-hold circuit can source at least the minimum high sustaining current at V<sub>IH</sub> min. I<sub>BHH</sub> should be measured after raising V<sub>IN</sub> to V<sub>CC</sub> and then lowering it to V<sub>IH</sub> min.

(5) An external driver must source at least I<sub>BHLO</sub> to switch this node from low to high.

(6) An external driver must sink at least I<sub>BHHO</sub> to switch this node from high to low.

(7) For I/O ports, the parameter I<sub>OZ</sub> includes the input leakage current.

**Electrical Characteristics (continued)**

 over recommended operating free-air temperature range (unless otherwise noted)<sup>(1)(2)</sup>

PARAMETER	TEST CONDITIONS	V <sub>CCA</sub>	V <sub>CCB</sub>	T <sub>A</sub> = 25°C			T <sub>A</sub> = -40°C to 85°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
I <sub>CCB</sub>	V <sub>I</sub> = V <sub>CCI</sub> or GND, I <sub>O</sub> = 0	1.2 V to 3.6 V	1.2 V to 3.6 V				25		μA
		0 V	3.6 V				25		
		3.6 V	0 V				-5		
I <sub>CCA</sub> + I <sub>CCB</sub>	V <sub>I</sub> = V <sub>CCI</sub> or GND, I <sub>O</sub> = 0	1.2 V to 3.6 V	1.2 V to 3.6 V				45		μA
C <sub>i</sub>	Control inputs V <sub>I</sub> = 3.3 V or GND	3.3 V	3.3 V		3.5				pF
C <sub>io</sub>	A or B port V <sub>O</sub> = 3.3 V or GND	3.3 V	3.3 V		7				pF

**7.6 Switching Characteristics: V<sub>CCA</sub> = 1.2 V**

 over recommended operating free-air temperature range, V<sub>CCA</sub> = 1.2 V (see Figure 11)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CCB</sub> = 1.2 V	V <sub>CCB</sub> = 1.5 V	V <sub>CCB</sub> = 1.8 V	V <sub>CCB</sub> = 2.5 V	V <sub>CCB</sub> = 3.3 V	UNIT
			TYP	TYP	TYP	TYP	TYP	
t <sub>PLH</sub>	A	B	4.1	3.3	3	2.8	3.2	ns
t <sub>PHL</sub>			4.1	3.3	3	2.8	3.2	
t <sub>PLH</sub>	B	A	4.4	4	3.8	3.6	3.5	ns
t <sub>PHL</sub>			4.4	4	3.8	3.6	3.5	
t <sub>PZH</sub>	$\overline{\text{OE}}$	A	6.4	6.4	6.4	6.4	6.4	ns
t <sub>PZL</sub>			6.4	6.4	6.4	6.4	6.4	
t <sub>PZH</sub>	$\overline{\text{OE}}$	B	6	4.6	4	3.4	3.2	ns
t <sub>PZL</sub>			6	4.6	4	3.4	3.2	
t <sub>PHZ</sub>	$\overline{\text{OE}}$	A	6.6	6.6	6.6	6.6	6.8	ns
t <sub>PLZ</sub>			6.6	6.6	6.6	6.6	6.8	
t <sub>PHZ</sub>	$\overline{\text{OE}}$	B	6	4.9	4.9	4.2	5.3	ns
t <sub>PLZ</sub>			6	4.9	4.9	4.2	5.3	



### 7.7 Switching Characteristics: $V_{CCA} = 1.5\text{ V} \pm 0.1\text{ V}$

over recommended operating free-air temperature range,  $V_{CCA} = 1.5\text{ V} \pm 0.1\text{ V}$  (see [Figure 11](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CCB} = 1.2\text{ V}$	$V_{CCB} = 1.5\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
$t_{PLH}$	A	B	3.6	0.5	6.2	0.5	5.2	0.5	4.1	0.5	3.7	ns
$t_{PHL}$			3.6	0.5	6.2	0.5	5.2	0.5	4.1	0.5	3.7	
$t_{PLH}$	B	A	3.3	0.5	6.2	0.5	5.9	0.5	5.6	0.5	5.5	ns
$t_{PHL}$			3.3	0.5	6.2	0.5	5.9	0.5	5.6	0.5	5.5	
$t_{PZH}$	$\overline{OE}$	A	4.3	1	10.1	1	10.1	1	10.1	1	10.1	ns
$t_{PZL}$			4.3	1	10.1	1	10.1	1	10.1	1	10.1	
$t_{PZH}$	$\overline{OE}$	B	5.6	1	10.1	0.5	8.1	0.5	5.9	0.5	5.2	ns
$t_{PZL}$			5.6	1	10.1	0.5	8.1	0.5	5.9	0.5	5.2	
$t_{PHZ}$	$\overline{OE}$	A	4.5	1.5	9.1	1.5	9.1	1.5	9.1	1.5	9.1	ns
$t_{PLZ}$			4.5	1.5	9.1	1.5	9.1	1.5	9.1	1.5	9.1	
$t_{PHZ}$	$\overline{OE}$	B	5.5	1.5	8.7	1.5	7.5	1	6.5	1	6.3	ns
$t_{PLZ}$			5.5	1.5	8.7	1.5	7.5	1	6.5	1	6.3	

### 7.8 Switching Characteristics: $V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$

over recommended operating free-air temperature range,  $V_{CCA} = 1.8\text{ V} \pm 0.15\text{ V}$  (see [Figure 11](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CCB} = 1.2\text{ V}$	$V_{CCB} = 1.5\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
$t_{PLH}$	A	B	3.4	0.5	5.9	0.5	4.8	0.5	3.7	0.5	3.3	ns
$t_{PHL}$			3.4	0.5	5.9	0.5	4.8	0.5	3.7	0.5	3.3	
$t_{PLH}$	B	A	3	0.5	5.2	0.5	4.8	0.5	4.5	0.5	4.4	ns
$t_{PHL}$			3	0.5	5.2	0.5	4.8	0.5	4.5	0.5	4.4	
$t_{PZH}$	$\overline{OE}$	A	3.4	1	7.8	1	7.8	1	7.8	1	7.8	ns
$t_{PZL}$			3.4	1	7.8	1	7.8	1	7.8	1	7.8	
$t_{PZH}$	$\overline{OE}$	B	5.4	1	9.2	0.5	7.4	0.5	5.3	0.5	4.5	ns
$t_{PZL}$			5.4	1	9.2	0.5	7.4	0.5	5.3	0.5	4.5	
$t_{PHZ}$	$\overline{OE}$	A	4.2	1.5	7.7	1.5	7.7	1.5	7.7	1.5	7.7	ns
$t_{PLZ}$			4.2	1.5	7.7	1.5	7.7	1.5	7.7	1.5	7.7	
$t_{PHZ}$	$\overline{OE}$	B	5.2	1.5	8.4	1.5	7.1	1	5.9	1	5.7	ns
$t_{PLZ}$			5.2	1.5	8.4	1.5	7.1	1	5.9	1	5.7	

### 7.9 Switching Characteristics: $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$

 over recommended operating free-air temperature range,  $V_{CCA} = 2.5\text{ V} \pm 0.2\text{ V}$  (see [Figure 11](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CCB} = 1.2\text{ V}$	$V_{CCB} = 1.5\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
$t_{PLH}$	A	B	3.2	0.5	5.6	0.5	4.5	0.5	3.3	0.5	2.8	ns
$t_{PHL}$			3.2	0.5	5.6	0.5	4.5	0.5	3.3	0.5	2.8	
$t_{PLH}$	B	A	2.6	0.5	4.1	0.5	3.7	0.5	3.3	0.5	3.2	ns
$t_{PHL}$			2.6	0.5	4.1	0.5	3.7	0.5	3.3	0.5	3.2	
$t_{PZH}$	$\overline{OE}$	A	2.5	0.5	5.3	0.5	5.3	0.5	5.3	0.5	5.3	ns
$t_{PZL}$			2.5	0.5	5.3	0.5	5.3	0.5	5.3	0.5	5.3	
$t_{PZH}$	$\overline{OE}$	B	5.2	0.5	9.4	0.5	7.3	0.5	5.1	0.5	4.5	ns
$t_{PZL}$			5.2	0.5	9.4	0.5	7.3	0.5	5.1	0.5	4.5	
$t_{PHZ}$	$\overline{OE}$	A	3	1	6.1	1	6.1	1	6.1	1	6.1	ns
$t_{PLZ}$			3	1	6.1	1	6.1	1	6.1	1	6.1	
$t_{PHZ}$	$\overline{OE}$	B	5	1	7.9	1	6.6	1	6.1	1	5.2	ns
$t_{PLZ}$			5	1	7.9	1	6.6	1	6.1	1	5.2	

### 7.10 Switching Characteristics: $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$

 over recommended operating free-air temperature range,  $V_{CCA} = 3.3\text{ V} \pm 0.3\text{ V}$  (see [Figure 11](#))

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CCB} = 1.2\text{ V}$	$V_{CCB} = 1.5\text{ V} \pm 0.1\text{ V}$		$V_{CCB} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CCB} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CCB} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
$t_{PLH}$	A	B	3.2	0.5	5.5	0.5	4.4	0.5	3.2	0.5	2.7	ns
$t_{PHL}$			3.2	0.5	5.5	0.5	4.4	0.5	3.2	0.5	2.7	
$t_{PLH}$	B	A	2.8	0.5	3.7	0.5	3.3	0.5	2.8	0.5	2.7	ns
$t_{PHL}$			2.8	0.5	3.7	0.5	3.3	0.5	2.8	0.5	2.7	
$t_{PZH}$	$\overline{OE}$	A	2.2	0.5	4.3	0.5	4.2	0.5	4.1	0.5	4	ns
$t_{PZL}$			2.2	0.5	4.3	0.5	4.2	0.5	4.1	0.5	4	
$t_{PZH}$	$\overline{OE}$	B	5.1	0.5	9.3	0.5	7.2	0.5	4.9	0.5	4	ns
$t_{PZL}$			5.1	0.5	9.3	0.5	7.2	0.5	4.9	0.5	4	
$t_{PHZ}$	$\overline{OE}$	A	3.4	0.5	5	0.5	5	0.5	5	0.5	5	ns
$t_{PLZ}$			3.4	0.5	5	0.5	5	0.5	5	0.5	5	
$t_{PHZ}$	$\overline{OE}$	B	4.9	1	7.7	1	6.5	1	5.2	0.5	5	ns
$t_{PLZ}$			4.9	1	7.7	1	6.5	1	5.2	0.5	5	

## 7.11 Operating Characteristics

 $T_A = 25^\circ\text{C}$ 

PARAMETER			TEST CONDITIONS	$V_{CCA} = V_{CCB} = 1.2\text{ V}$	$V_{CCA} = V_{CCB} = 1.5\text{ V}$	$V_{CCA} = V_{CCB} = 1.8\text{ V}$	$V_{CCA} = V_{CCB} = 2.5\text{ V}$	$V_{CCA} = V_{CCB} = 3.3\text{ V}$	UNIT
				TYP	TYP	TYP	TYP	TYP	
$C_{pdA}^{(1)}$	A to B	Outputs enabled	$C_L = 0,$ $f = 10\text{ MHz},$ $t_r = t_f = 1\text{ ns}$	1	1	1	1	2	pF
		Outputs disabled		1	1	1	1	1	
	B to A	Outputs enabled		13	13	14	15	16	
		Outputs disabled		1	1	1	1	1	
$C_{pdB}^{(1)}$	A to B	Outputs enabled		13	13	14	15	16	pF
		Outputs disabled		1	1	1	1	1	
	B to A	Outputs enabled		1	1	1	1	2	
		Outputs disabled		1	1	1	1	1	

(1) Power dissipation capacitance per transceiver. Refer to the TI application report, *CMOS Power Consumption and Cpd Calculation*, [SCAA035](#)

7.12 Typical Characteristics ( $T_A = 25^\circ\text{C}$ )

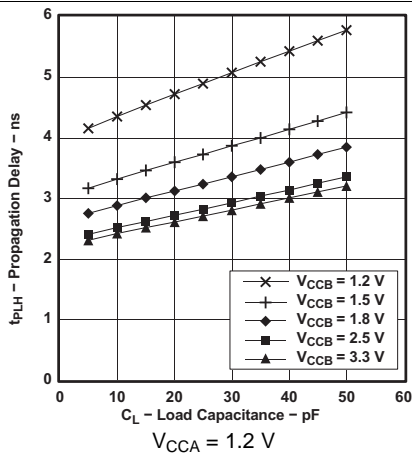


Figure 1. Typical Propagation Delay  $t_{PLH}$  (A to B) vs Load Capacitance

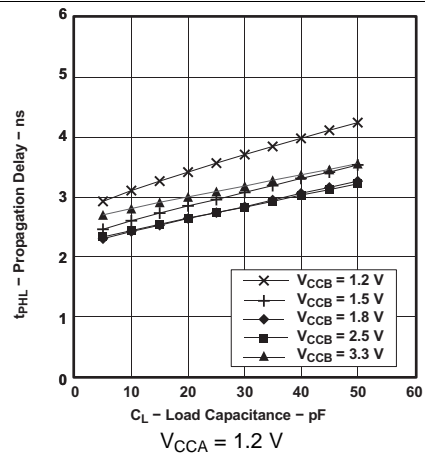


Figure 2. Typical Propagation Delay  $t_{PHL}$  (A to B) vs Load Capacitance

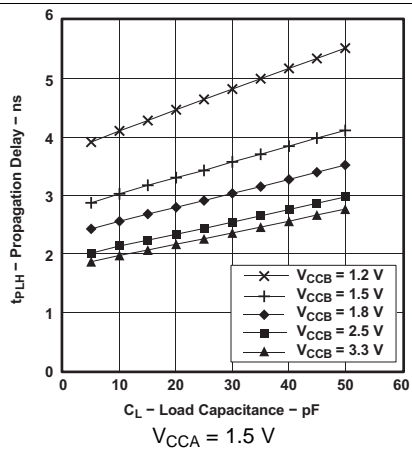


Figure 3. Typical Propagation Delay  $t_{PLH}$  (A to B) vs Load Capacitance

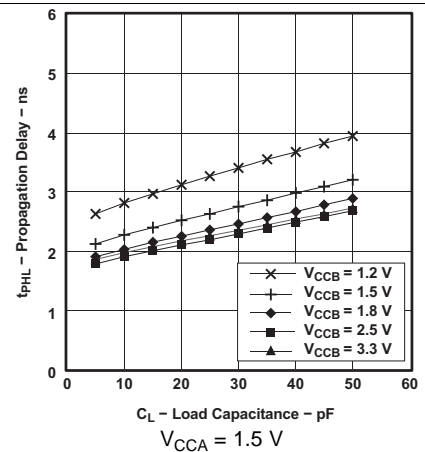


Figure 4. Typical Propagation Delay  $t_{PHL}$  (A to B) vs Load Capacitance

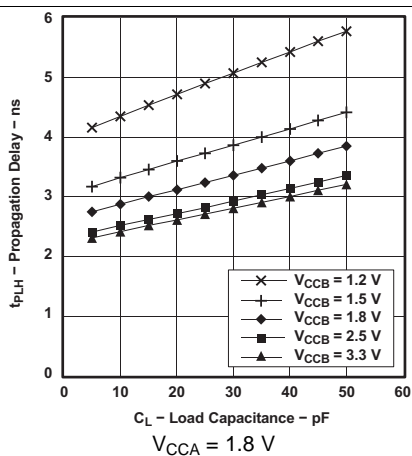


Figure 5. Typical Propagation Delay  $t_{PLH}$  (A to B) vs Load Capacitance

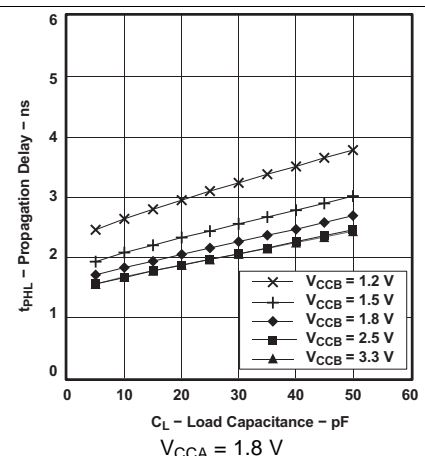


Figure 6. Typical Propagation Delay  $t_{PHL}$  (A to B) vs Load Capacitance

Typical Characteristics ( $T_A = 25^\circ\text{C}$ ) (continued)

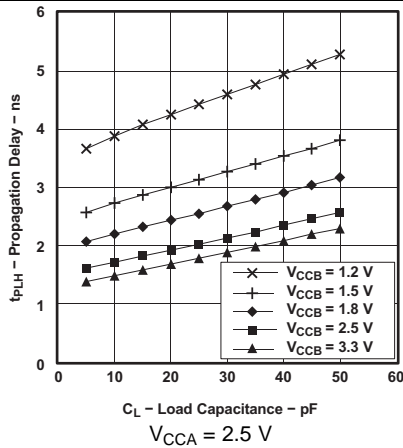


Figure 7. Typical Propagation Delay  $t_{PLH}$  (A to B) vs Load Capacitance

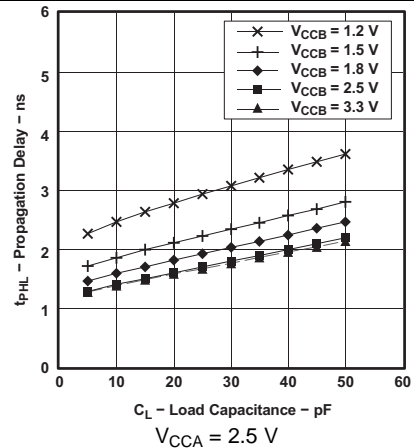


Figure 8. Typical Propagation Delay  $t_{PHL}$  (A to B) vs Load Capacitance

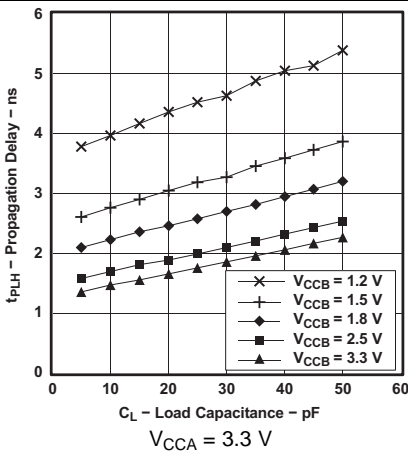


Figure 9. Typical Propagation Delay  $t_{PLH}$  (A to B) vs Load Capacitance

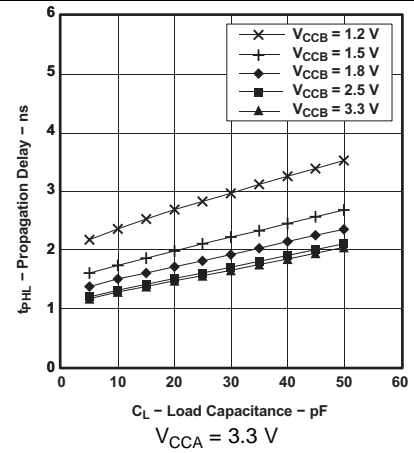
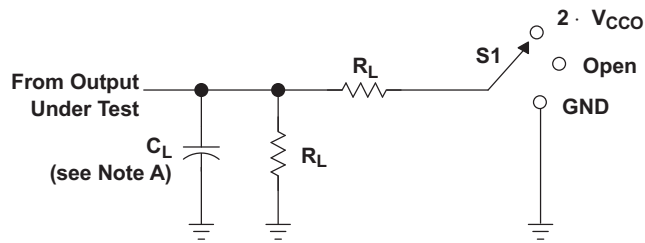


Figure 10. Typical Propagation Delay  $t_{PHL}$  (A to B) vs Load Capacitance

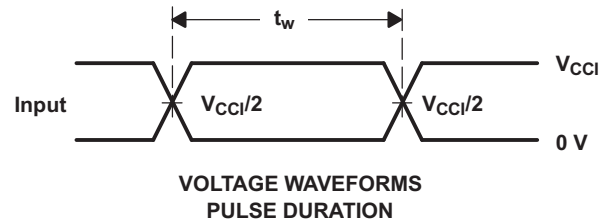
## 8 Parameter Measurement Information



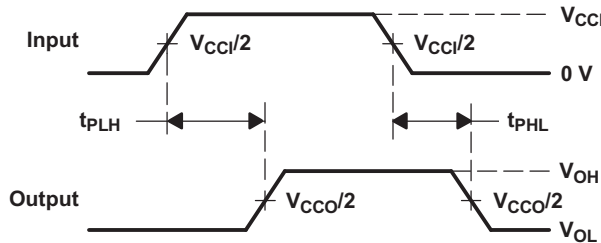
LOAD CIRCUIT

TEST	S1
$t_{pd}$	Open
$t_{PLZ}/t_{PZL}$	$2 \cdot V_{CCO}$
$t_{PHZ}/t_{PZH}$	GND

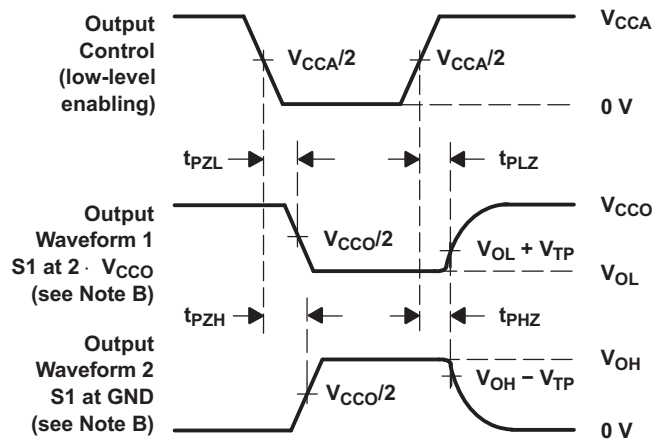
$V_{CCO}$	$C_L$	$R_L$	$V_{TP}$
1.2 V	15 pF	2 k $\Omega$	0.1 V
1.5 V $\pm$ 0.1 V	15 pF	2 k $\Omega$	0.1 V
1.8 V $\pm$ 0.15 V	15 pF	2 k $\Omega$	0.15 V
2.5 V $\pm$ 0.2 V	15 pF	2 k $\Omega$	0.15 V
3.3 V $\pm$ 0.3 V	15 pF	2 k $\Omega$	0.3 V



VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES

- NOTES:
- A.  $C_L$  includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR = 10 MHz,  $Z_O = 50 \Omega$ ,  $dv/dt \geq 1$  V/ns.
  - D. The outputs are measured one at a time, with one transition per measurement.
  - E.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
  - F.  $V_{CCI}$  is the  $V_{CC}$  associated with the input port.
  - G.  $V_{CCO}$  is the  $V_{CC}$  associated with the output port.

Figure 11. Load Circuit and Voltage Waveforms

## 9 Detailed Description

### 9.1 Overview

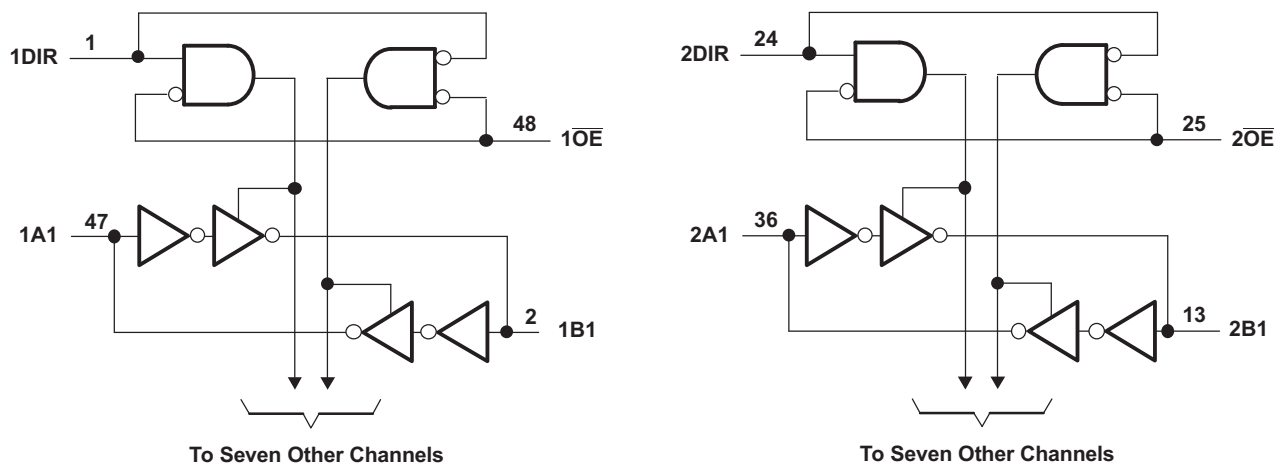
The SN74AVCH16T245 is a 16-bit, dual-supply noninverting bidirectional voltage level translation. Pins A and control pins (DIR and  $\overline{OE}$ ) are supported by  $V_{CCA}$  and pins B are supported by  $V_{CCB}$ . The A port can accept I/O voltages ranging from 1.2 V to 3.6 V, while the B port can accept I/O voltages from 1.2 V to 3.6 V. A high on DIR allows data transmission from A to B and a low on DIR allows data transmission from B to A when  $\overline{OE}$  is set to low. When  $\overline{OE}$  is set to high, both A and B are in the high-impedance state.

SN74AVCH16T245 features Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

This device is fully specified for partial-power-down applications using off output current ( $I_{off}$ ).

The  $V_{CC}$  isolation feature ensures that if either  $V_{CC}$  input is at GND, both ports are put in a high-impedance state.

### 9.2 Functional Block Diagram



### 9.3 Feature Description

#### 9.3.1 Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.2 V to 3.6 V Power-Supply Range

Both  $V_{CCA}$  and  $V_{CCB}$  can be supplied at any voltage from 1.2 V to 3.6 V making the device suitable for translating between any of the low voltage nodes (1.2 V, 1.8 V, 2.5 V, and 3.3 V).

#### 9.3.2 Partial-Power-Down Mode Operation

The  $I_{off}$  circuitry will prevent backflow current by disabling I/O output circuits when device is in partial power-down mode. This device is fully specified for partial-power-down applications using off output current ( $I_{off}$ ). The  $I_{off}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### 9.3.3 $V_{CC}$ Isolation

The  $V_{CC}$  isolation feature ensures that if either  $V_{CCA}$  or  $V_{CCB}$  are at GND, both ports will be in a high-impedance state ( $I_{OZ}$  shown in [Electrical Characteristics](#)). This prevents false logic levels from being presented to either bus.

## 9.4 Device Functional Modes

The SN74AVCH16T245 is a voltage level translator that can operate from 1.2 V to 3.6 V ( $V_{CCA}$ ) and 1.2 V to 3.6 V ( $V_{CCB}$ ). The signal translation between 1.2 V and 3.6 V requires direction control and output enable control. When  $\overline{OE}$  is low and DIR is high, data transmission is from A to B. When  $\overline{OE}$  is low and DIR is low, data transmission is from B to A. When  $\overline{OE}$  is high, both output ports will be high-impedance.

**Table 1. Function Table  
(Each Transceiver)**

INPUTS		OPERATION
$\overline{OE}$	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation

**Table 2. Typical Total Static Power Consumption ( $I_{CCA} + I_{CCB}$ )**

$V_{CCB}$	$V_{CCA}$						UNIT
	0 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
0 V	0	< 0.5	< 0.5	< 0.5	< 0.5	< 0.5	μA
1.2 V	< 0.5	< 1	< 1	< 1	< 1	1	
1.5 V	< 0.5	< 1	< 1	< 1	< 1	1	
1.8 V	< 0.5	< 1	< 1	< 1	< 1	< 1	
2.5 V	< 0.5	1	< 1	< 1	< 1	< 1	
3.3 V	< 0.5	1	< 1	< 1	< 1	< 1	



## 10 Application and Implementation

### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

### 10.1 Application Information

The SN74AVCH16T245 device can be used in level-shifting applications for interfacing devices and addressing mixed voltage incompatibility. The SN74AVCH16T245 device is ideal for data transmission where direction is different for each channel.

### 10.2 Typical Application

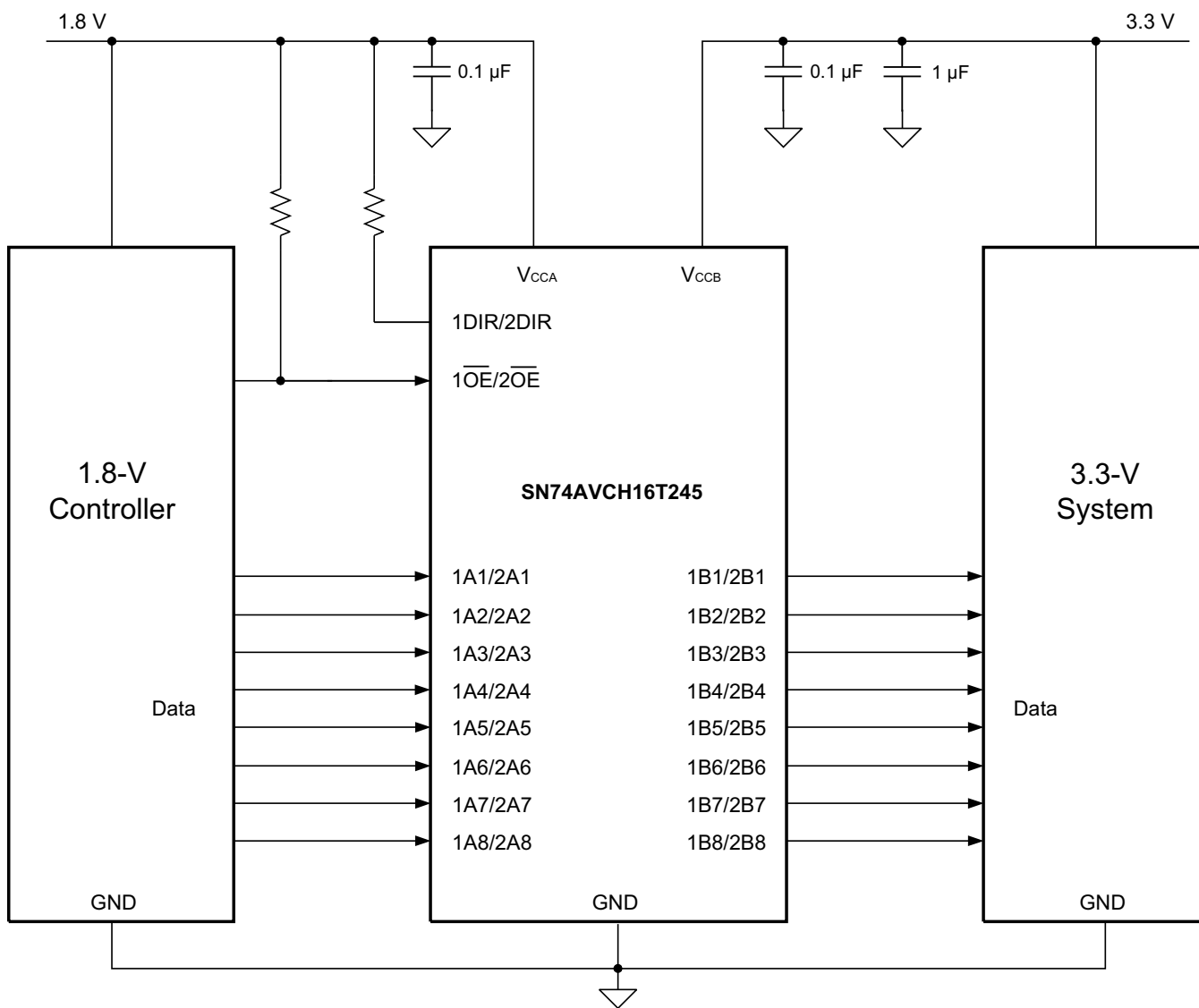


Figure 12. Typical Application Schematic

## Typical Application (continued)

### 10.2.1 Design Requirements

This device uses drivers which are enabled depending on the state of the DIR pin. The designer must know the intended flow of data and take care not to violate any of the high or low logic levels. Unused data inputs are must not be floating, as this can cause excessive internal leakage on the input CMOS structure. Tie any unused input and output ports directly to ground.

For this design example, use the parameters listed in [Table 3](#).

**Table 3. Design Parameters**

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage range	1.2 V to 3.6 V
Output voltage range	1.2 V to 3.6 V

### 10.2.2 Detailed Design Procedure

To begin the design process, determine the following:

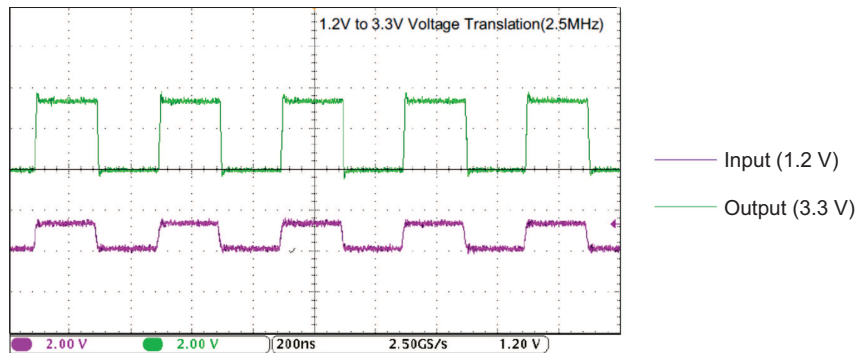
#### 10.2.2.1 Input Voltage Ranges

Use the supply voltage of the device that is driving the SN74AVCH16T245 device to determine the input voltage range. For a valid logic high the value must exceed the  $V_{IH}$  of the input port. For a valid logic low the value must be less than the  $V_{IL}$  of the input port.

#### 10.2.2.2 Output Voltage Range

Use the supply voltage of the device that the SN74AVCH16T245 device is driving to determine the output voltage range.

### 10.2.3 Application Curve



**Figure 13. Translation Up (1.2 V to 3.3 V) at 2.5 MHz**

## 11 Power Supply Recommendations

The SN74AVCH16T245 device uses two separate configurable power-supply rails,  $V_{CCA}$  and  $V_{CCB}$ .  $V_{CCA}$  accepts any supply voltage from 1.2 V to 3.6 V and  $V_{CCB}$  accepts any supply voltage from 1.2 V to 3.6 V. The A port and B port are designed to track  $V_{CCA}$  and  $V_{CCB}$ , respectively, allowing for low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V and 3.3-V voltage nodes.

The output-enable  $\overline{OE}$  input circuit is supplied by  $V_{CCA}$  and when the  $\overline{OE}$  input is high, all outputs are placed in the high-impedance state. To ensure the high-impedance state of the outputs during power up or power down, the  $\overline{OE}$  input pin must be tied to  $V_{CCA}$  through a pullup resistor and must not be enabled until  $V_{CCA}$  and  $V_{CCB}$  are fully ramped and stable. The minimum value of the pullup resistor to  $V_{CCA}$  is determined by the current-sinking capability of the driver.

## 12 Layout

### 12.1 Layout Guidelines

To ensure reliability of the device, following common printed-circuit board layout guidelines is recommended.

- Bypass capacitors should be used on power supplies.
- Short trace lengths should be used to avoid excessive loading.
- Placing pads on the signal paths for loading capacitors or pullup resistors to help adjust rise and fall times of signals depending on the system requirements.

## 12.2 Layout Example

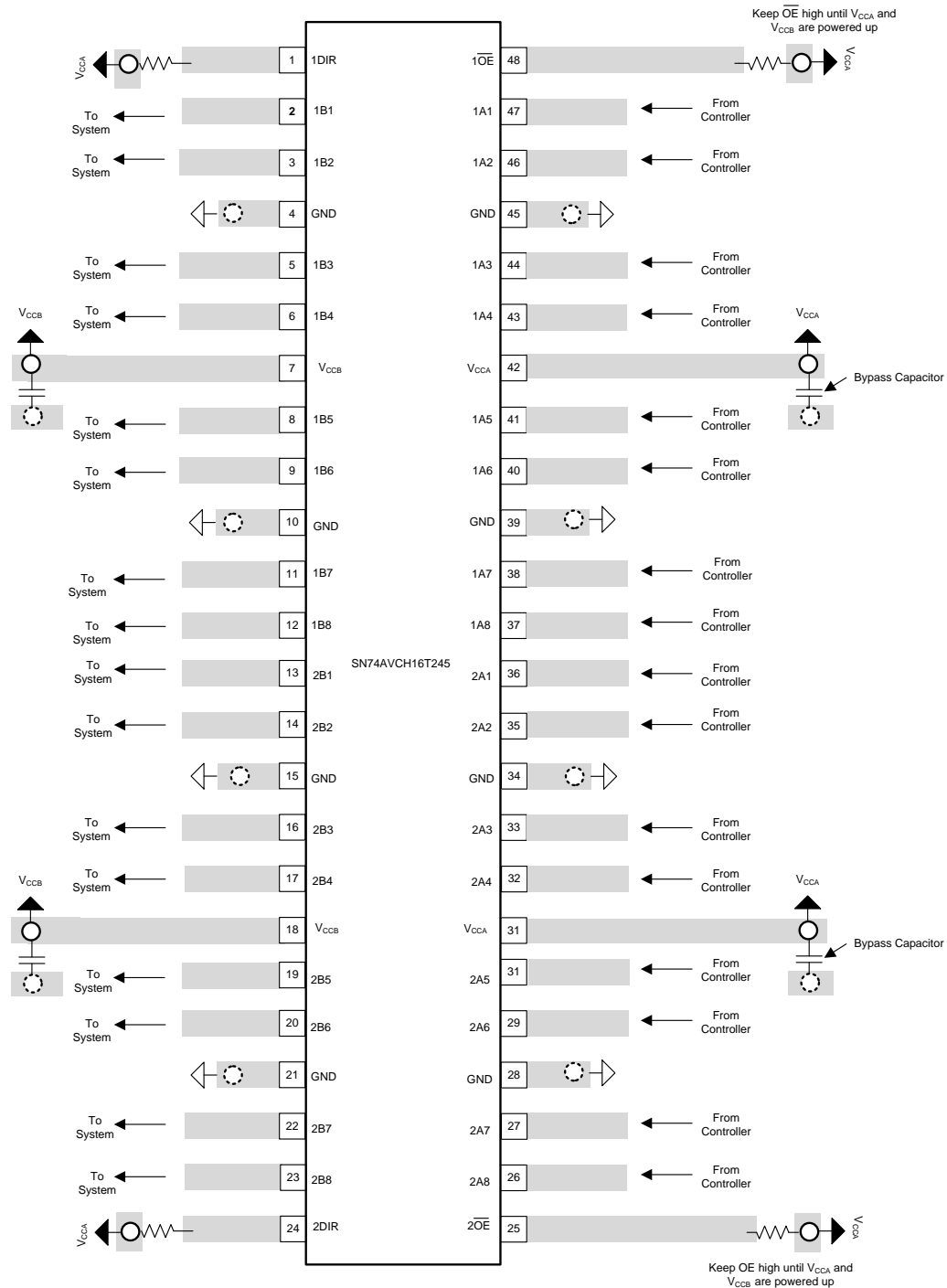
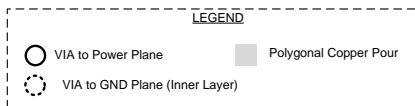


Figure 14. Recommended Layout Example

## 13 Device and Documentation Support

### 13.1 Documentation Support

#### 13.1.1 Related Documentation

For related documentation see the following:

- *CMOS Power Consumption and Cpd Calculation*, [SCAA035](#)
- *Implications of Slow or Floating CMOS Inputs*, [SCBA004](#)

### 13.2 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's [Terms of Use](#).

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All other trademarks are the property of their respective owners.

### 13.4 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

### 13.5 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

## 14 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

**PACKAGING INFORMATION**

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
74AVCH16T245ZQLR	ACTIVE	BGA MICROSTAR JUNIOR	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	WJ245	<a href="#">Samples</a>
SN74AVCH16T245GR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	AVCH16T245	<a href="#">Samples</a>
SN74AVCH16T245VR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	WJ245	<a href="#">Samples</a>

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBsolete:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

**Green (RoHS & no Sb/Br):** TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**TAPE AND REEL INFORMATION**

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
74AVCH16T245ZQLR	BGA MICROSTAR JUNIOR	ZQL	56	1000	330.0	16.4	4.8	7.3	1.5	8.0	16.0	Q1
SN74AVCH16T245GR	TSSOP	DGG	48	2000	330.0	24.4	8.6	13.0	1.8	12.0	24.0	Q1
SN74AVCH16T245VR	TVSOP	DGV	48	2000	330.0	16.4	7.1	10.2	1.6	12.0	16.0	Q1



**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
74AVCH16T245ZQLR	BGA MICROSTAR JUNIOR	ZQL	56	1000	336.6	336.6	28.6
SN74AVCH16T245GR	TSSOP	DGG	48	2000	367.0	367.0	45.0
SN74AVCH16T245VR	TVSOP	DGV	48	2000	367.0	367.0	38.0

DGV (R-PDSO-G\*\*)

PLASTIC SMALL-OUTLINE

24 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.  
 D. Falls within JEDEC: 24/48 Pins – MO-153  
 14/16/20/56 Pins – MO-194

DGG (R-PDSO-G\*\*)

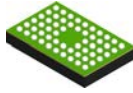
PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.  
 B. This drawing is subject to change without notice.  
 C. Body dimensions do not include mold protrusion not to exceed 0,15.  
 D. Falls within JEDEC MO-153

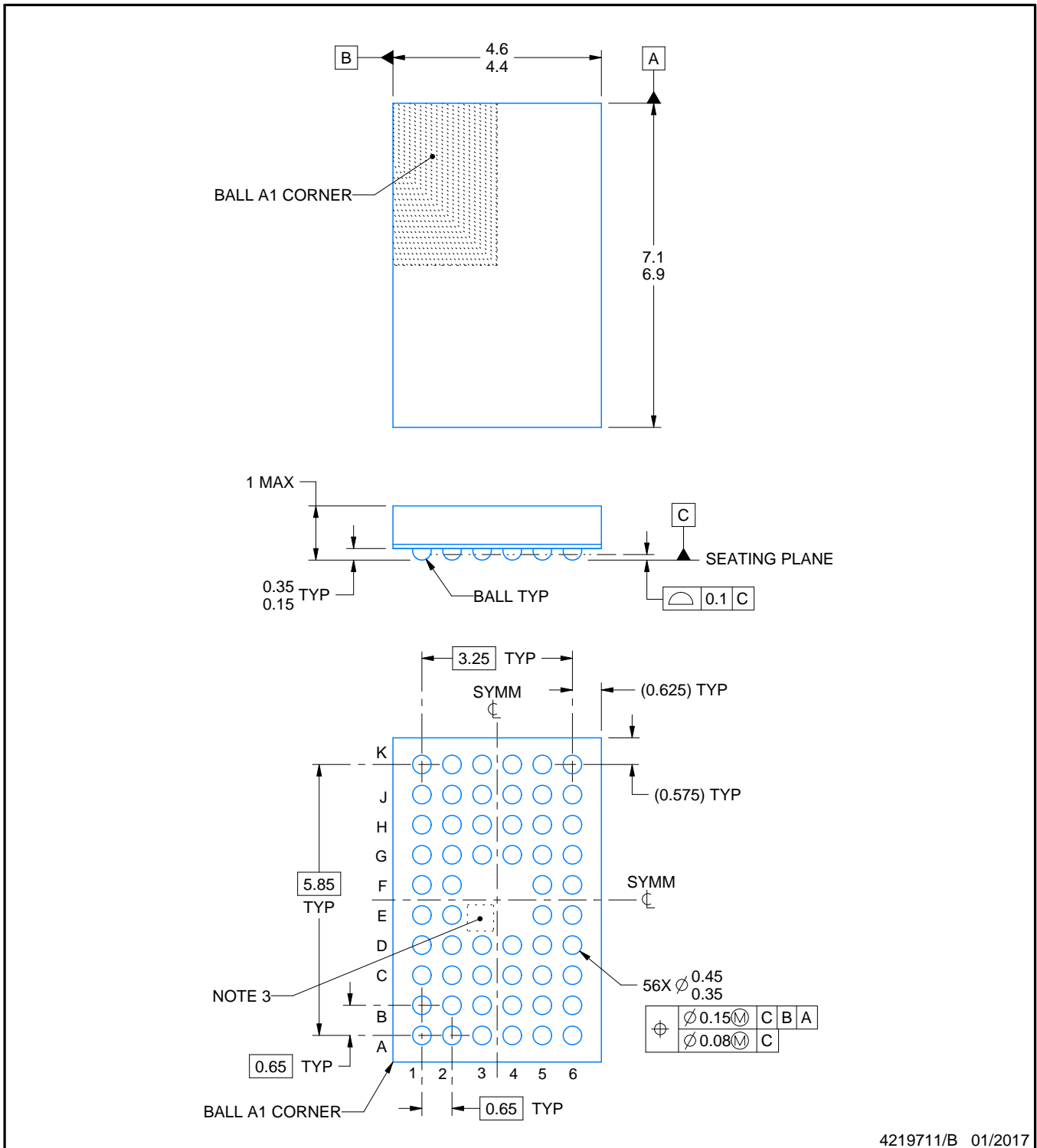
# ZQL0056A



## PACKAGE OUTLINE

JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



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### NOTES:

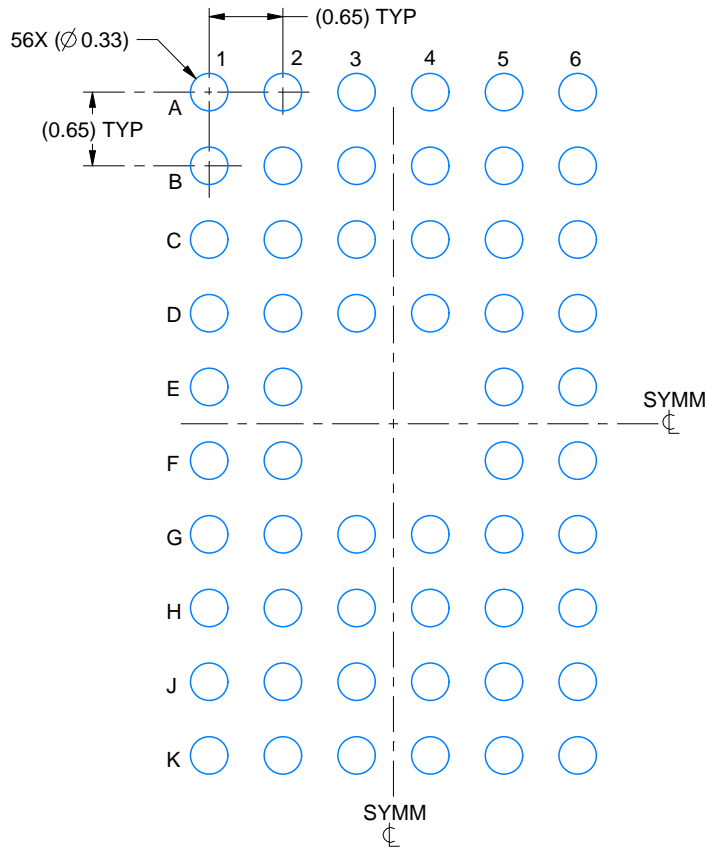
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. No metal in this area, indicates orientation.

# EXAMPLE BOARD LAYOUT

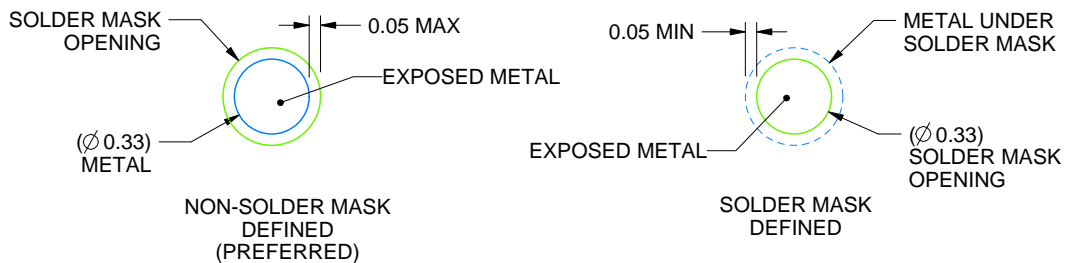
ZQL0056A

JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



LAND PATTERN EXAMPLE  
EXPOSED METAL SHOWN  
SCALE:15X



SOLDER MASK DETAILS  
NOT TO SCALE

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NOTES: (continued)

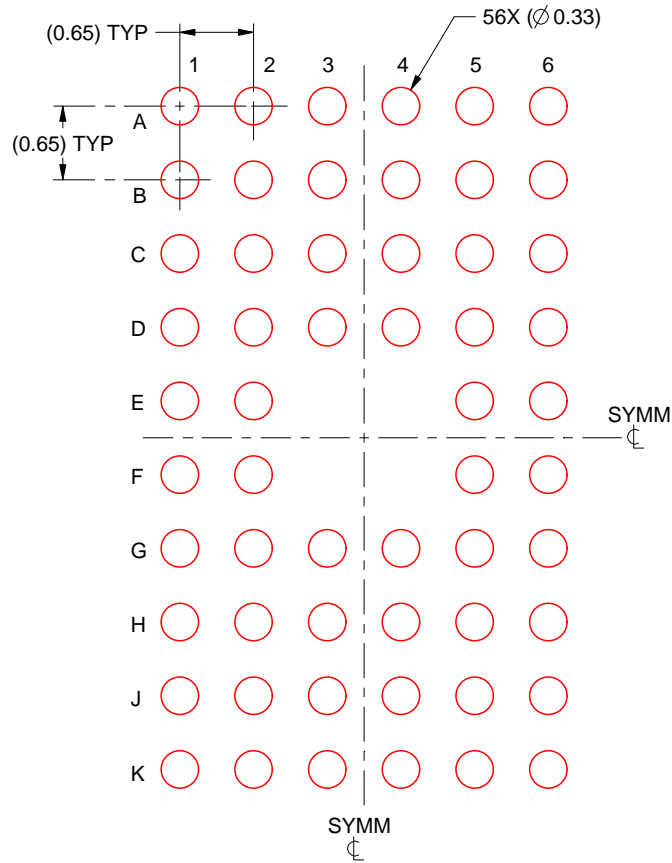
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For information, see Texas Instruments literature number SPRAA99 ([www.ti.com/lit/spraa99](http://www.ti.com/lit/spraa99)).

# EXAMPLE STENCIL DESIGN

ZQL0056A

JRBGA - 1 mm max height

PLASTIC BALL GRID ARRAY



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:15X

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NOTES: (continued)

5. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.